

FZT560

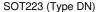
500V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > -500V
- I_C = -150mA High Continuous Current
- I_{CM} = -500mA Peak Pulse Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (FZT560Q)

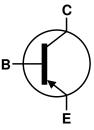
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 63
- Weight: 0.112 grams (Approximate)

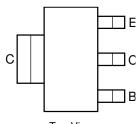








Device Symbol



Top View Pin-Out

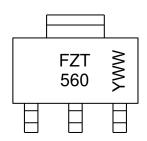
Ordering Information (Note 4)

Part Number	Dookogo	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Part Number	Package	Warking	neer Size (iliches)	rape widin (ililii)	Qty.	Carrier
FZT560TA	SOT223 (Type DN)	FZT560	7	12	1,000	Reel
FZT560TC	SOT223 (Type DN)	FZT560	13	12	4,000	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FZT 560 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 3 = 2023) WW or $\overline{W}W$ = Week Code (01 to 53)



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-500	V
Collector-Emitter Voltage	VCEO	-500	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	lc	-150	mA
Peak Pulse Current	Ісм	-500	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Dower Dissipation	(Note 5)	D-	2	W
Power Dissipation	(Note 6)	P _D	3	W
Thermal Decistance Junction to Ambient	(Note 5)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		Rejl	14.8	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	٧	С

Notes:

- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 6. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

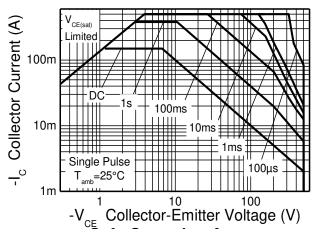


Figure 1. Safe Operating Area

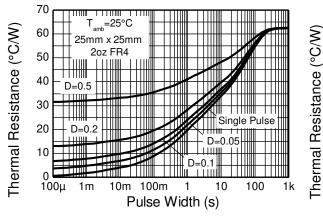


Figure 2. Transient Thermal Impedance

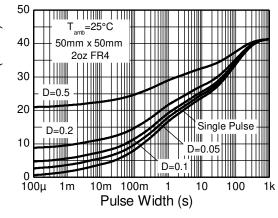


Figure 3. Transient Thermal Impedance

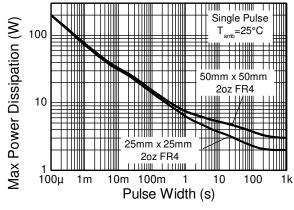


Figure 4. Pulse Power Dissipation

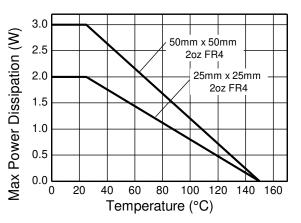


Figure 5. Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-500	_	_	V	Ic = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BVCEO	-500	_	_	V	Ic = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	_	_	V	I _E = -100μA
Collector Cut-Off Current	Ісво	_	_	-100	nA	V _{CB} = -500V
Collector Cut-Off Current	ICES	_	_	-100	nA	Vce = -500V
Emitter Cut-Off Current	IEBO	_	_	-100	nA	V _{EB} = -5.6V
Collector Emitter Seturation Valtage (Note 0)	V _{CE(sat)}	_	_	-200	mV	$I_C = -20mA, I_B = -2mA$
Collector-Emitter Saturation Voltage (Note 9)		_	_	-500		$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	_	-900	mV	Ic = -50mA, I _B = -10mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	-900	mV	Ic = -50mA, VcE = -10V
		100	_	300		Ic = -1mA, VcE = -10V
DC Current Gain (Note 9)	hfE	80	_	300	_	$I_C = -50$ mA, $V_{CE} = -10$ V
		_	15	_		$I_C = -100 \text{mA}, V_{CE} = -10 \text{V}$
Current Gain-Bandwidth Product	f⊤	60	_	_	MHz	V _{CE} = -20V, I _C = -10mA f = 50MHz
Turn-On Time	ton	_	110	_	ns	V _{CC} = -100V, I _C = -50mA
Turn-Off Time	toff	_	1.5	_	μs	$I_{B1} = -5mA$, $I_{B2} = 10mA$
Output Capacitance	Cobo		_	8	рF	V _{CB} = -20V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

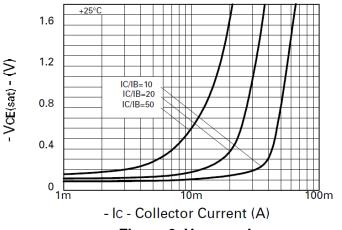


Figure 6. VCE(sat) v IC

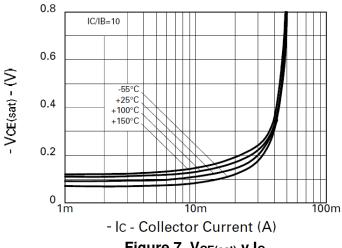


Figure 7. V_{CE(sat)} v I_C

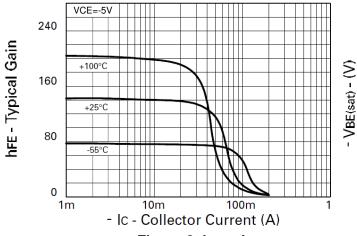


Figure 8. hfe v lc

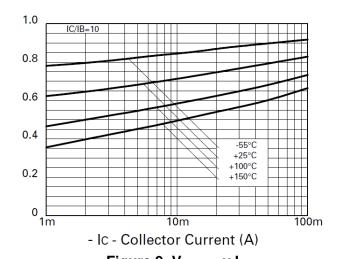


Figure 9. V_{BE(sat)} v I_C

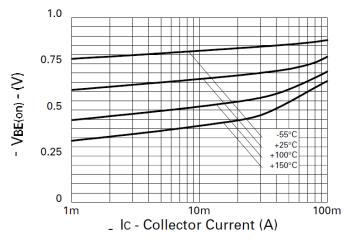


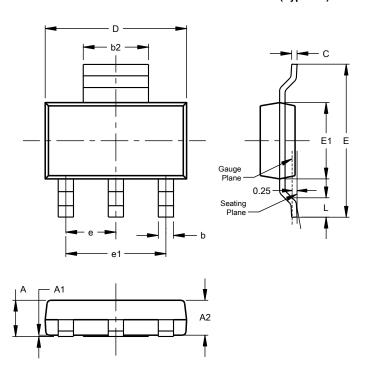
Figure 10. VBE(on) v Ic



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

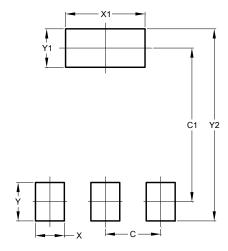


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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